NSN 5962-01-043-1614

Memory Microcircuit - Page 1 of 1



view Online at https://aerobasegroup.com/nsn/5962-01-043-1614
Body Length:
Between 1.180 inches and 1.220 inches
Body Width:
Between 0.560 inches and 0.600 inches
Body Height:
Between 0.100 inches and 0.140 inches
Maximum Power Dissipation Rating:
2.0 watts
Operating Tempurature Range:
-55.0/+85.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and negative outputs and positive outputs and w/enable and w/buffered output and programmable and
programmed and expandable and w/decoded output and 3-state output and wire-or outputs and high speed
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
P-type metal oxide-semiconductor logic
Input Circuit Pattern:
10 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
48.0 volts power source
Time Rating Per Chacteristic:
1000.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Test Data Document:
28815-17-123497 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Fiig: A458a0

Demilitarization: Yes - demil/mli